

April 2010

# MJD45H11 PNP Epitaxial Silicon Transistor

### **Applications**

- · General Purpose Power and Switching Such as Output or Driver Stages in Applications
- · D-PAK for Surface Mount Applications

### **Features**

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK: "-I" Suffix)
- Electrically Similar to Popular MJE45H
- · Fast Switching Speeds
- Low Collector Emitter Saturation Voltage



### **Absolute Maximum Ratings** T<sub>A</sub> = 25°C unless otherwise noted

| Symbol           | Parameter                                    | Value        | Units |
|------------------|--|--------------|-------|
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | - 80         | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | - 5          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | - 8          | Α     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | - 16         | A     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 20           | W     |
|                  | Collector Dissipation (T <sub>A</sub> =25°C) | 1.75         | W     |
| TJ               | Junction Temperature                         | 150          | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 to +150 | °C    |

### **Electrical Characteristics** T<sub>A</sub> = 25°C unless otherwise noted

| Symbol                 | Parameter                             | Test Condition   | Min.     | Тур. | Max.  | Units |
|------------------------|---------------------------------------|--|----------|------|-------|-------|
| V <sub>CEO</sub> (sus) | *Collector-Emitter Sustaining Voltage | I <sub>C</sub> = - 30mA, I <sub>B</sub> = 0  | - 80     |      |       | V     |
| I <sub>CEO</sub>       | Collector Cut-off Current             | $V_{CE} = -80V, I_{B} = 0$   |          |      | - 10  | μА    |
| I <sub>EBO</sub>       | Emitter Cut-off Current               | $V_{BE} = -5V, I_{C} = 0$  |          |      | - 50  | μА    |
| h <sub>FE</sub>        | *DC Current Gain                      | V <sub>CE</sub> = - 1V, I <sub>C</sub> = - 2A<br>V <sub>CE</sub> = - 1V, I <sub>C</sub> = - 4A | 60<br>40 |      |       |       |
| V <sub>CE</sub> (sat)  | *Collector-Emitter Saturation Voltage | I <sub>C</sub> = -8A, I <sub>B</sub> = -0.4A   |          |      | - 1   | V     |
| V <sub>BE</sub> (on)   | *Base-Emitter Saturation Voltage      | I <sub>C</sub> = -8A, I <sub>B</sub> = -0.8A   |          |      | - 1.5 | V     |
| f <sub>T</sub>         | Current Gain Bandwidth Product        | V <sub>CE</sub> = - 10A, I <sub>C</sub> = - 0.5A   |          | 40   |       | MHz   |
| C <sub>ob</sub>        | Collector Capacitance                 | V <sub>CB</sub> = - 10V, f = 1MHz  |          | 230  |       | pF    |
| t <sub>ON</sub>        | Turn On Time                          |  |          | 135  |       | ns    |
| t <sub>STG</sub>       | Storage Time                          | I <sub>C</sub> = - 5A<br>I <sub>B1</sub> = - I <sub>B2</sub> = - 0.5A                          |          | 500  |       | ns    |
| t <sub>F</sub>         | Fall Time                             | -D1 -DZ 0.07.  |          | 100  |       | ns    |

<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%

© 2010 Fairchild Semiconductor Corporation

MJD45H11 Rev. C3

www.fairchildsemi.com

### **Typical Performance Characteristics**

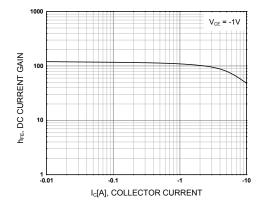


Figure 1. DC current Gain

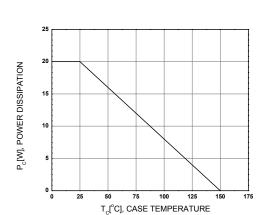


Figure 3. Power Derating vs  $T_{\text{C}}$ 

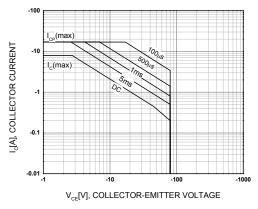


Figure 2. Safe Operating Area

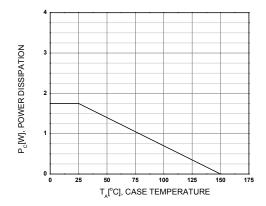
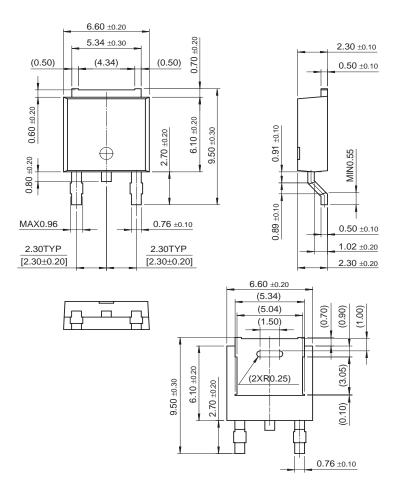


Figure 4. Power Derating vs  $T_A$ 

### **Physical Dimension**

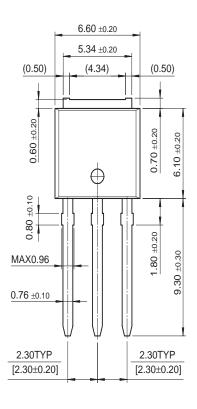
# D-PAK

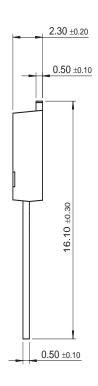


Dimensions in Millimeters

### Physical Dimension (Continued)

## I-PAK







Dimensions in Millimeters





#### **TRADEMARKS**

Dual Cool™

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

FRFET® AccuPower™ Auto-SPM™ Global Power Resource SM Build it Now™ Green FPS™ Green FPS™ e-Series™ CorePLUS™ CorePOWER™ Gmax™  $CROSSVOLT^{\text{\tiny TM}}$ GTO™ CTL™ IntelliMAX™ Current Transfer Logic™ ISOPLANAR™ DEUXPEED® MegaBuck™

MICROCOUPLER™ EcoSPARK® MicroFET™ EfficientMax™ MicroPak™ MicroPak2™ MillerDrive™ Fairchild® MotionMax™ Fairchild Semiconductor® Motion-SPM™ FACT Quiet Series™ OptoHiT™ FACT<sup>®</sup> OPTOLOGIC® FAST® **OPTOPLANAR®** FastvCore™

FlashWriter®\* PDP SPM™ FPS™ Power-SPM™ F-PFS™

PowerTrench® PowerXS™

Programmable Active Droop™

OFĔT QS™ Quiet Series™ RapidConfigure™ **○**TM

Saving our world, 1mW/W/kW at a time™

SignalWise™ SmartMax™ SMART START™ SPM<sup>®</sup> STEALTH™ SuperFET™ . SuperSOT™-3 SuperSOT™-6 . SuperSOT™-8 SupreMOS™

. SyncFET™ Sync-Lock™ SYSTEM ®\* The Power Franchise®

puwer TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic<sup>®</sup> TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™

TriFault Detect™

TRUECURRENT™\*

μSerDes™ UHC Ultra FRFET™ UniFFT™ VCXTM VisualMax™

XS TM

\* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FETBench™

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN: NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS. NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com,

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications. and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

| Product Status        | Definition  |  |  |  |  |  |
|-----------------------|---|--|--|--|--|--|
| Formative / In Design | Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.   |  |  |  |  |  |
| First Production      | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. |  |  |  |  |  |
| Full Production       | Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.   |  |  |  |  |  |
| Not In Production     | Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.  |  |  |  |  |  |
|                       | Formative / In Design First Production Full Production  |  |  |  |  |  |

Rev. 147